NSN 5961-01-626-6083

Unitized Semiconductor Devices - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-626-6083 **Inclosure Material:** Plastic **Overall Length:** 2.15 inches **Terminal Length:** 0.40 inches **Overall Height:** 1.05 inches **Overall Width:** 2.10 inches **Function For Which Designed:** Switching **Response Time:** 4.0 nanoseconds 1st semiconductor device diode **Component Name And Quantity:** 3 semiconductor device diode **Mounting Method: Terminal Semiconductor Material:** Silicon 1st semiconductor device diode Voltage Rating In Volts Per Characteristic: 75.0 repetitive peak reverse voltage 1st semiconductor device diode **Current Rating Per Characteristic:** 1.0 milliamperes peak nonrepetitive reverse current 1st semiconductor device diode **Power Rating Per Characteristic:** 200.0 milliwatts off-state power dissipation 1st semiconductor device diode **Capacitance Rating In Picofarads:** 2.0 1st semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 25.0 degrees celsius ambient air **Product Name:** Surface mount, fast switching, diode array **Special Features:** Rohs compliant and lead free **Terminal Type And Quantity:** 6 tab, solder lug Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

No

NSN 5961-01-626-6083

Unitized Semiconductor Devices - Page 2 of 2



Fiig:

A110a0